• Please type a plu	s sign (+) Inside this box	·→[-	JUN 2 1 200	Re B		
7				Complete If Known		
Substitute for form 1449A/B/PTO			Ribert	Application Number	10/811,979	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)				Filing Date	March 30, 2004	
				First Named Inventor	KAMIYAMA	
				Group Art Unit	2814	
				Examiner Name	L. Pham	
Shoot	1	Of	*	Attorney Docket Number	403018	

OTHER • NON PATENT LITERATURE DOCUMENTS										
Examiner Initials	Doc. No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number (s), publisher, city and/or country where published.	Trans Yes	No*+						
1.0	D 1	HOBBS, C. et al.; "Fermi Level Pinning at the PolySi/Metal Oxide Interface", 2003								
		Symposium of VLSI Tech. Digest of Technical Papers, pp. 3-4.								
			ļ							
			_							
			-							
			<del> </del>							
			<del> </del>							
			ļ							
				L						
Evaminer	Τ	Date 4/2///								

<sup>\*</sup> A concise statement of relevance is being submitted in lieu of a translation. 37 CFR 1.98(a)(3).